









SN74LV8T245-Q1 SCLS908A - DECEMBER 2022 - REVISED APRIL 2023

# SN74LV8T245-Q1 Automotive 1.65 V to 5 V, Octal Bus Transceiver With 3-State **Outputs and Logic Level Shifter**

#### 1 Features

- AEC-Q100 qualified for automotive applications:
  - Device temperature grade 1:
    - -40°C to +125°C, T<sub>A</sub>
  - Device HBM ESD Classification Level 2
  - Device CDM ESD Classification Level C6
- Wide operating range of 1.8 V to 5.5 V
- Available in wettable flank QFN (WRKS) package
- Single-supply voltage translator (refer to LVxT Enhanced Input Voltage):
  - Up translation:
    - 1.2 V to 1.8 V
    - 1.5 V to 2.5 V
    - 1.8 V to 3.3 V
    - 3.3 V to 5.0 V
  - Down translation:
    - 5.0 V, 3.3 V, 2.5 V to 1.8 V
    - 5.0 V. 3.3 V to 2.5 V
    - 5.0 V to 3.3 V
- 5.5 V tolerant input pins
- Supports standard pinouts
- Up to 150 Mbps with 5 V or 3.3 V  $V_{CC}$
- Latch-up performance exceeds 250 mA per JESD 17

## 2 Applications

- Enable or disable a digital signal
- Eliminate slow or noisy input signals
- Hold a signal during controller reset
- Debounce a switch

# 3 Description

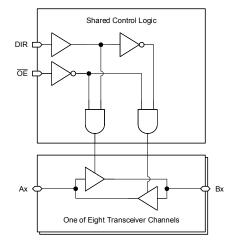
The SN74LV8T245-Q1 is an octal bus transceiver with 3-state outputs. All eight channels are controlled by the direction (DIR) pin and output enable  $(\overline{OE})$ pin. The output level is referenced to the supply voltage (V<sub>CC</sub>) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

The input is designed with a lower threshold circuit to support up translation for lower voltage CMOS inputs (for example, 1.2 V input to 1.8 V output or 1.8 V input to 3.3 V output). Additionally, the 5-V tolerant input pins enable down translation (for example, 3.3 V to 2.5 V output).

#### Package Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	RKS (VQFN, 20)	4.50 mm × 2.50 mm		
SN74LV8T245-Q1	DGS (VSSOP, 20)	5.10 mm × 3.00 mm		
	PW (TSSOP, 20)	6.50 mm × 4.40 mm		

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Logic Diagram (Positive Logic)



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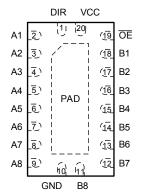
# **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

# Changes from Revision \* (December 2022) to Revision A (April 2023)Page• Changed the status of the data sheet from: Advanced Information to: Production Data1



# **5 Pin Configuration and Functions**



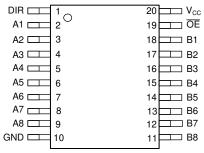


Figure 5-2. DGS or PW Package, 20-Pin VSSOP or TSSOP (Top View)

Figure 5-1. RKS Package, 20-Pin VQFN (Transparent Top View)

Table 5-1. Pin Functions

P	PIN	TYPE(1)	DESCRIPTION
NAME	NO.	IYPE	DESCRIPTION
DIR	1	I	Direction control input (L = B $\rightarrow$ A, H = A $\rightarrow$ B)
A1	2	I/O	Channel 1 output/input A
A2	3	I/O	Channel 2 output/input A
A3	4	I/O	Channel 3 output/input A
A4	5	I/O	Channel 4 output/input A
A5	6	I/O	Channel 5 output/input A
A6	7	I/O	Channel 6 output/input A
A7	8	I/O	Channel 7 output/input A
A8	9	I/O	Channel 8 output/input A
GND	10	G	Ground
B8	11	I/O	Channel 8 input/output B
B7	12	I/O	Channel 7 input/output B
B6	13	I/O	Channel 6 input/output B
B5	14	I/O	Channel 5 input/output B
B4	15	I/O	Channel 4 input/output B
B3	16	I/O	Channel 3 input/output B
B2	17	I/O	Channel 2 input/output B
B1	18	I/O	Channel 1 input/output B
ŌĒ	19	I	Output enable, active low
V <sub>CC</sub>	20	Р	Positive supply
Thermal Pad <sup>(2</sup>	t)	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.

- (1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power
- (2) RKS package only



# **6 Specifications**

# **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	nput voltage range <sup>(2)</sup>			V
V	Output voltage range <sup>(2)</sup>	Output voltage range <sup>(2)</sup>			V
Vo	Voltage range applied to any outp	-0.5	4.6	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < -0.5 V		-20	mA
I <sub>OK</sub>	Output clamp current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V		±20	mA
Io	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±25	mA
	Continuous output current through		±50	mA	
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

## 6.2 ESD Ratings

			VALUE	UNIT	
	Clastication .	Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2		±4000	
V <sub>(ESD)</sub>	discharge	Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±2000	V	

(1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



# **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)(1)

Spec	Description	Condition	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.6	5.5	V
V <sub>I</sub>	Input Voltage		0	5.5	V
V <sub>O</sub>	Output Voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V to 2 V	1.1		
,	High-level input voltage	V <sub>CC</sub> = 2.25 V to 2.75 V	1.28		V
/ <sub>IH</sub>	nigri-ievei iriput voitage	V <sub>CC</sub> = 3 V to 3.6 V	1.45		V
		V <sub>CC</sub> = 4.5 V to 5.5 V	2		
		V <sub>CC</sub> = 1.65 V to 2 V		0.51	
,	Low Lovel input veltage	V <sub>CC</sub> = 2.25 V to 2.75 V		0.65	V
/ <sub>IL</sub>	Low-Level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		0.75	V
		V <sub>CC</sub> = 4.5 V to 5.5 V		0.80	
		V <sub>CC</sub> = 1.65 V to 2.0 V		±3	
0	Output Current	V <sub>CC</sub> = 2.25 V to 2.75 V		±7	mA
		V <sub>CC</sub> = 3.3 V to 5.0 V		±15	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 1.6 V to 5.5 V		20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND for proper device operation. Refer to the TI application report, Implications of Slow or FLoating CMOS Inputs.

# **6.4 Thermal Information**

			SN74LV8T245-Q1		
THERMAL METRIC(1)		RKS (VQFN) DGS (VSSOF		PW (TSSOP)	UNIT
		20 PINS	20 PINS	20 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	67.7	118.4	122.3	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	72.4	57.7	64.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.4	73.1	73.3	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	10.3	5.7	19.0	°C/W
$Y_{JB}$	Junction-to-board characterization parameter	40.4	72.7	73.0	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	24.1	N/A	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



#### **6.5 Electrical Characteristics**

over operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	` ,	T <sub>A</sub>	= 25°C		-40°C	to 125°C		UNIT
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	TYP	MAX	UNII
	I <sub>OH</sub> = -50 μA	1.65 V to 5.5 V	V <sub>CC</sub> -0.1			V <sub>CC</sub> -0.1			
	I <sub>OH</sub> = -2 mA	1.65 V	1.28	1.6 <sup>(1)</sup>		1.21			
V <sub>OH</sub>	I <sub>OH</sub> = -3 mA	2.25 V	2	2.3 <sup>(1)</sup>		1.93			V
	I <sub>OH</sub> = -5.5 mA	3.0 V	2.6	3.08 <sup>(1)</sup>		2.49			
	I <sub>OH</sub> = -8 mA	4.5 V	4.1	4.65 <sup>(1)</sup>		3.95			
	I <sub>OL</sub> = 50 μA	1.65 V to 5.5 V			0.1			0.1	
	I <sub>OL</sub> = 2 mA	1.65 V		0.15 <sup>(1)</sup>	0.2			0.25	
V <sub>OL</sub>	I <sub>OL</sub> = 3 mA	2.25 V		0.15 <sup>(1)</sup>	0.17			0.2	V
	I <sub>OL</sub> = 5.5 mA	3.0 V		0.20(1)	0.23			0.25	
	I <sub>OH</sub> = 8 mA	4.5 V		0.30(1)	0.3			0.35	
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	1.65 V to 5.5 V			1			10	μA
	One input at 0.3 V or 3.4 V, other inputs at V <sub>CC</sub> or GND	5.5 V			1.35			1.5	mA
$\Delta_{\rm ICC}$	One input at 0.3 V or 1.1 V, other inputs at V <sub>CC</sub> or GND	1.8 V			20			20	μΑ
II	V <sub>I</sub> = 0 V to V <sub>CC</sub>	$V_I = 0 V \text{ to } V_{CC}$			±0.1			±1	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			±0.25			±2.5	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		2	10		2	10	pF
Co	Vo = V <sub>CC</sub> or GND	3.3 V		5			5		pF
C <sub>PD</sub> (2) (3)	CL = 50 pF, F = 10 MHz	1.65 V to 5.5 V		16					pF

- Typical value at nearest nominal voltage (1.8 V; 2.5 V; 3.3 V; 5 V)
- (2) C<sub>PD</sub> is used to determine the dynamic power consumption, per channel
   (3) P<sub>D</sub>= V<sub>CC</sub> <sup>2</sup>xF<sub>I</sub>X(C<sub>PD</sub>+ C<sub>L</sub>) where F<sub>I</sub>= input frequency, C<sub>L</sub>= output load capacitance, V<sub>CC</sub>= supply voltage

# 6.6 Switching Characteristics - 1.8-V V<sub>CC</sub>

over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information

PARAME	EDOM (INDUT)	TO (OUTPUT)	LOAD	T <sub>A</sub> = 25°	С	-40°	C to 125°C	UNIT
TER	FROM (INPUT)		CAPACITANCE	MIN TYP	MAX	MIN	TYP MAX	UNII
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 15 pF	11.8	3 22	1	25.1	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF	16.4	27.2	1	32.6	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF	16.4	24.8	1	30	nS
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 50 pF	15.6	27	1	31	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF	19.5	30.9	1	38	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF	24.1	31.4	1	36.6	nS
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF		2.5		2.5	nS

# 6.7 Switching Characteristics - 2.5-V V<sub>CC</sub>

over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information

PARAME	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			-40°C to 125°C			UNIT
TER	TROM (INTOT)			MIN	TYP	MAX	MIN	TYP	MAX	ONIT
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 15 pF		8.8	13.5	1		17.5	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		12.3	20.4	1		24.5	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		12.3	18.6	1		22.5	nS
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 50 pF		11.7	16.4	1		21.5	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		14.6	23.2	1		28.5	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		18.1	23.6	1		27.5	nS
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF			2			2	nS

# 6.8 Switching Characteristics - 3.3-V $V_{\text{CC}}$

over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information

PARAME	FROM (INPUT)	TO (OUTPUT)	LOAD	T <sub>A</sub> = 25°C			-40°0	С	UNIT	
TER	PROM (INPUT)		CAPACITANCE	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 15 pF		6.4	8.9	1		11.5	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		9	13.7	1		17	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		10.1	17	1		21	nS
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 50 pF		8.8	12.4	1		15	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		11.5	17.2	1		20.5	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		14.4	20.3	1		23.5	nS
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF			1.5			1.5	nS

# 6.9 Switching Characteristics - 5-V V<sub>CC</sub>

over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information

PARAME	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			-40°C to 125°C			UNIT
TER	PROW (INPUT)			MIN	TYP	MAX	MIN	TYP	MAX	ONT
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 15 pF		4.5	7.7	1		10	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		8.9	13.8	1		16	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF		9.2	14.4	1		16.5	nS
t <sub>Pd</sub>	A or B	B or A	C <sub>L</sub> = 50 pF		5.3	8.7	1		11	nS
t <sub>en</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		9.7	14.8	1		17	nS
t <sub>dis</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF		10	15.4	1		17.5	nS
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF			1			1	nS

#### **6.10 Noise Characteristics**

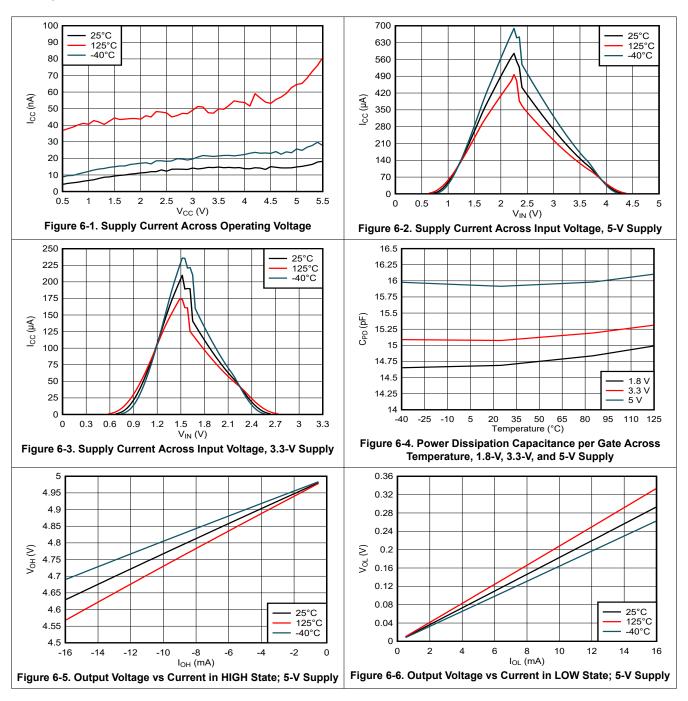
 $V_{CC} = 5 \text{ V. } C_1 = 50 \text{ pF. } T_{\Delta} = 25^{\circ} \text{C}^{(1)}$ 

VCC UV, UL	00 pr, r <sub>A</sub> = 20 0 · ·				
PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		1		V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.6		V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		4		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

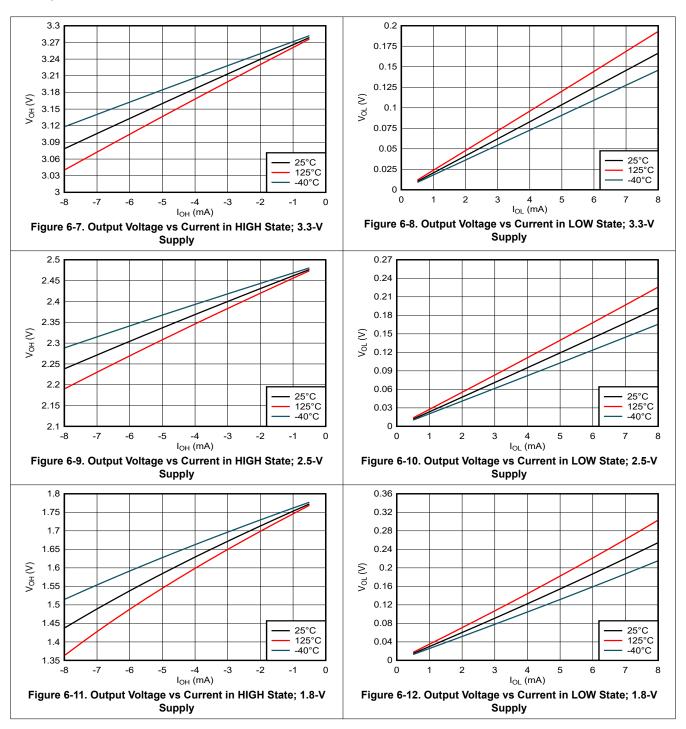
(1) Characteristics are for surface-mount packages only



## 6.11 Typical Characteristics



# **6.11 Typical Characteristics (continued)**



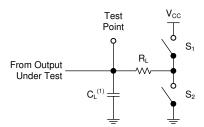


## 7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ .

For clock inputs,  $f_{\text{max}}$  is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C<sub>L</sub> includes probe and test-fixture capacitance.

Figure 7-1. Load Circuit for 3-State Outputs

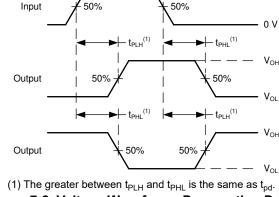
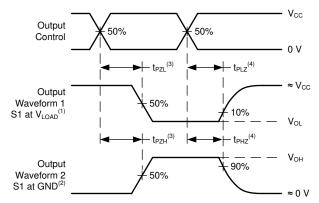
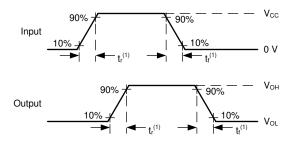


Figure 7-2. Voltage Waveforms Propagation Delays



- (1) S1 = CLOSED, S2 = OPEN.
- (2) S1 = OPEN, S2 = CLOSED.
- (3) The greater between t<sub>PZL</sub> and t<sub>PZH</sub> is the same as t<sub>en</sub>.
- (4) The greater between t<sub>PLZ</sub> and t<sub>PHZ</sub> is the same as t<sub>dis</sub>.

Figure 7-3. Voltage Waveforms Propagation Delays



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

Figure 7-4. Voltage Waveforms, Input and Output Transition Times

## 8 Detailed Description

#### 8.1 Overview

The SN74LV8T245-Q1 is an octal bus transceiver with 3-state outputs. All eight channels are controlled by the direction (DIR) pin and output enable  $(\overline{OE})$  pin. Each transceiver includes one buffer oriented from Ax to Bx and one from Bx to Ax, with at least one output disabled at all times. The direction (DIR) pin controls which buffer is active. The buffer that is not active has the output placed into the high-impedance state.

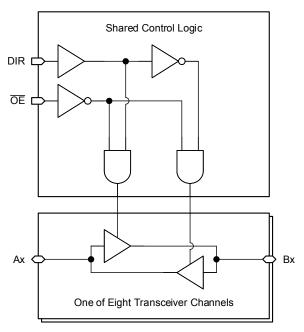
The output enable  $(\overline{OE})$  controls all outputs in the device. When the  $\overline{OE}$  pin is in the low state, the appropriate outputs as determined by the direction (DIR) pin are enabled. When the  $\overline{OE}$  pin is in the high state, all outputs of the device are disabled. All disabled outputs are placed into the high-impedance state.

To ensure the high-impedance state during power up or power down, the  $\overline{\text{OE}}$  pin should be tied to  $V_{CC}$  through a pull-up resistor; the minimum value of the resistor is determined by the current sinking capability of the driver and the leakage of the pin as defined in the *Electrical Characteristics* table. Typically a 10-k $\Omega$  resistor will be sufficient.

The output level is referenced to the supply voltage ( $V_{CC}$ ) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

The input is designed with a lower threshold circuit to support up translation for lower voltage CMOS inputs (for example 1.2 V input to 1.8 V output or 1.8 V input to 3.3 V output). Additionally, the 5-V tolerant input pins enable down translation (for example 3.3 V to 2.5 V output).

## 8.2 Functional Block Diagram



#### 8.3 Feature Description

#### 8.3.1 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device can drive larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance mode, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a 10-k $\Omega$  resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

#### 8.3.2 Clamp Diode Structure

The outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only as depicted in Figure 8-1.

#### **CAUTION**

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

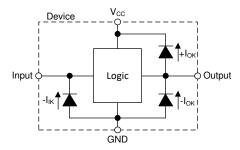


Figure 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

#### 8.3.3 LVxT Enhanced Input Voltage

The SN74LV8T245-Q1 belongs to TIs LVxT family of Logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5 V levels to support down-translation. The output voltage will always be referenced to the supply voltage ( $V_{CC}$ ), as described in the *Electrical Characteristics* table. For proper functionality, input signals must remain at or below the specified  $V_{IH(MIN)}$  level for a HIGH input state, and at or below the specified  $V_{IL(MAX)}$  for a LOW input state. Figure 8-2 shows the typical  $V_{IH}$  and  $V_{IL}$  levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law ( $R = V \div I$ ).

The inputs require that input signals transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at  $V_{CC}$  or GND. If a system will not be actively driving an input at all times, a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; a 10-k $\Omega$  resistor, however, is recommended and will typically meet all requirements.

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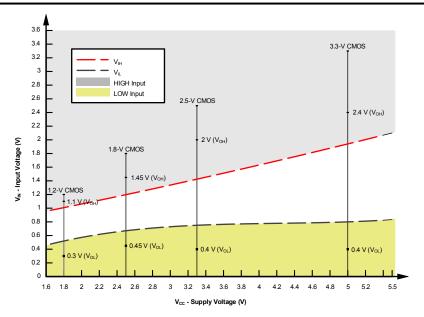


Figure 8-2. LVxT Input Voltage Levels

#### 8.3.3.1 Down Translation

Signals can be translated down using the SN74LV8T245-Q1. The voltage applied at the  $V_{CC}$  will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state. Ensure that the input signals in the HIGH state are between  $V_{IH(MIN)}$  and 5.5 V, and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in Figure 8-2.

For example, standard CMOS inputs for devices operating at 5.0 V, 3.3 V, or 2.5 V can be down-translated to match 1.8 V CMOS signals when operating from 1.8-V  $V_{CC}$ . See Figure 8-3.

#### **Down Translation Combinations:**

- 1.8-V V<sub>CC</sub> Inputs from 2.5 V, 3.3 V, and 5.0 V
- 2.5-V V<sub>CC</sub> Inputs from 3.3 V and 5.0 V
- 3.3-V V<sub>CC</sub> Inputs from 5.0 V

## 8.3.3.2 Up Translation

Input signals can be up translated using the SN74LV8T245-Q1. The voltage applied at  $V_{CC}$  will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables. When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state.

The inputs have reduced thresholds that allow for input high-state levels which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5-V supply will have a  $V_{IH(MIN)}$  of 3.5 V. For the SN74LV8T245-Q1,  $V_{IH(MIN)}$  with a 5-V supply is only 2 V, which would allow for up-translation from typical 2.5-V to 5-V signals.

Ensure that the input signals in the HIGH state are above  $V_{IH(MIN)}$  and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in Figure 8-3.

#### Up Translation Combinations:

- 1.8-V V<sub>CC</sub> Inputs from 1.2 V
- 2.5-V V<sub>CC</sub> Inputs from 1.8 V
- 3.3-V V<sub>CC</sub> Inputs from 1.8 V and 2.5 V
- 5.0-V V<sub>CC</sub> Inputs from 2.5 V and 3.3 V



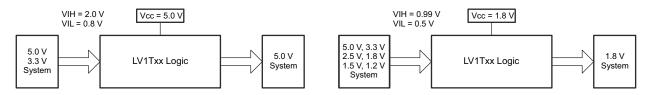


Figure 8-3. LVxT Up and Down Translation Example

#### 8.3.4 Wettable Flanks

This device includes wettable flanks for at least one package. See the *Features* section on the front page of the data sheet for which packages include this feature.

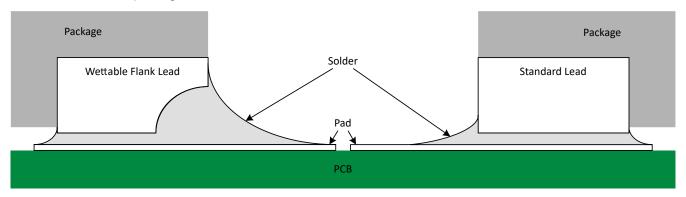


Figure 8-4. Simplified Cutaway View of Wettable-Flank QFN Package and Standard QFN Package After Soldering

Wettable flanks help improve side wetting after soldering, which makes QFN packages easier to inspect with automatic optical inspection (AOI). As shown in Figure 8-4, a wettable flank can be dimpled or step-cut to provide additional surface area for solder adhesion which assists in reliably creating a side fillet. See the mechanical drawing for additional details.

## 8.4 Device Functional Modes

Table 8-1 lists the functional modes of the SN74LV8T245-Q1.

**Table 8-1. Function Table** 

INPU	ITS <sup>(1)</sup>	OUTPUTS <sup>(2)</sup>			
ŌĒ	DIR	Α	В		
L	L	В	Z		
L	Н	Z	Α		
Н	Х	Z	Z		

- (1) H = High voltage level, L = Low voltage level, X = Do not care
- (2) A = Logic value at 'A' input, B = Logic value at 'B' input, Z = High impedance

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# 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

The SN74LV8T245-Q1 can be used to drive signals over relatively long traces or transmission lines. To reduce ringing caused by impedance mismatches between the driver, transmission line, and receiver, a series damping resistor placed in series with the transmitter's output can be used. The figure in the *Application Curve* section shows the received signal with three separate resistor values. Just a small amount of resistance can make a significant impact on signal integrity in this type of application.

## 9.2 Typical Application

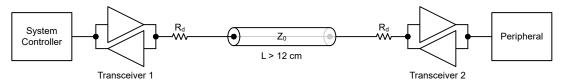


Figure 9-1. Application Block Diagram

# 9.3 Design Requirements

#### 9.3.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics*.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV8T245-Q1 plus the maximum static supply current,  $I_{CC}$ , listed in the *Electrical Characteristics* and any transient current required for switching. The logic device can only source as much current as is provided by the positive supply source. Be sure not to exceed the maximum total current through  $V_{CC}$  listed in the *Absolute Maximum Ratings*.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV8T245-Q1 plus the maximum supply current, I<sub>CC</sub>, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current as can be sunk into its ground connection. Be sure not to exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN74LV8T245-Q1 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

The SN74LV8T245-Q1 can drive a load with total resistance described by  $R_L \ge V_O$  /  $I_O$ , with the output voltage and current defined in the *Electrical Characteristics* table with  $V_{OH}$  and  $V_{OL}$ . When outputting in the high state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the  $V_{CC}$  pin.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and Cpd Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

#### CAUTION

The maximum junction temperature,  $T_{J(max)}$  listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

#### 9.3.2 Input Considerations

Input signals must cross  $V_{IL(max)}$  to be considered a logic LOW, and  $V_{IH(min)}$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74LV8T245-Q1, as specified in the *Electrical Characteristics*, and the desired input transition rate. A 10-k $\Omega$  resistor value is often used due to these factors.

The SN74LV8T245-Q1 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the Feature Description section for additional information regarding the inputs for this device.

#### 9.3.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OL}$  specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V<sub>CC</sub> or ground.

Refer to Feature Description section for additional information regarding the outputs for this device.



#### 9.3.4 Detailed Design Procedure

- Add a decoupling capacitor from V<sub>CC</sub> to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V<sub>CC</sub> and GND pins. An example layout is shown in the *Layout* section.
- 2. Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit; it will, however, ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74LV8T245-Q1 to one or more of the receiving devices.
- 3. Ensure the resistive load at the output is larger than  $(V_{CC} / I_{O(max)}) \Omega$ . This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in M $\Omega$ ; much larger than the minimum calculated previously.
- 4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, *CMOS Power Consumption and Cpd Calculation*.

## 9.4 Application Curves

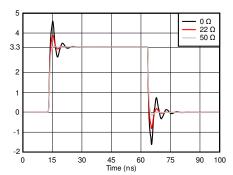


Figure 9-2. Simulated Signal Integrity at the Receiver With Different Damping Resistor (R<sub>d</sub>) Values

# 10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.



## 11 Layout

# 11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 11.2 Layout Example

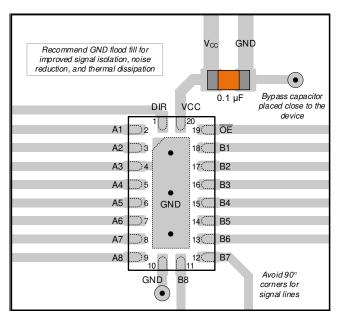


Figure 11-1. Example Layout for the SN74LV8T245-Q1 in RKS



## 12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### **12.1 Documentation Support**

#### 12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, CMOS Power Consumption and Cpd Calculation application report
- Texas Instruments, Designing With Logic application report

## 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 12.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 12.4 Trademarks

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#### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 1-Nov-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
74LV8T245QWRKSRQ1	Active	Production	VQFN (RKS)   20	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8245Q
74LV8T245QWRKSRQ1.A	Active	Production	VQFN (RKS)   20	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8245Q
SN74LV8T245QDGSRQ1	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8245Q
SN74LV8T245QDGSRQ1.A	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8245Q
SN74LV8T245QDGSRQ1.B	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	-	Call TI	Call TI	-40 to 125	
SN74LV8T245QPWRQ1	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T245Q
SN74LV8T245QPWRQ1.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T245Q

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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# PACKAGE OPTION ADDENDUM

www.ti.com 1-Nov-2025

#### OTHER QUALIFIED VERSIONS OF SN74LV8T245-Q1:

● Catalog : SN74LV8T245

NOTE: Qualified Version Definitions:

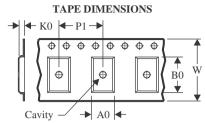
Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Jul-2025

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74LV8T245QWRKSRQ1	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1
SN74LV8T245QDGSRQ1	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74LV8T245QPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

www.ti.com 24-Jul-2025



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74LV8T245QWRKSRQ1	VQFN	RKS	20	3000	210.0	185.0	35.0
SN74LV8T245QDGSRQ1	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74LV8T245QPWRQ1	TSSOP	PW	20	2000	353.0	353.0	32.0





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

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- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.





#### NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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